

## T495A155K016ATE5K0

T495, Tantalum, MnO2 Tantalum, Commercial Grade, 1.5 uF, 10%, 16 VDC, SMD, MnO2, Molded, Low ESR, 5 Ohms, 3216, 1.8 mm, 0.8 mm

T495

MnO2 Tantalum

SMD, MnO2, Molded, Low ESR

SMD Chip

Low ESR

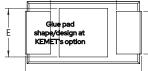
CATHODE (-) END VIEW



ANODE (+) END VIEW

ΗB S - G - S -

SIDE VIEW



Click here for the

BOTTOM VIEW	RoHS	Yes
	Termination	Tin
	AEC-Q200	No
	Typical Component Weight	58.6 mg
	Shelf Life	156 Weeks
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3D model.		
	Specifications	
2mm +/-0.2mm	Capacitance	1.5 uF
6mm +/-0.2mm	Tolerance	10%
6mm +/-0.2mm 6mm +/-0.2mm	Tolerance Voltage DC	10% 16 VDC (85C), 1
•		
6mm +/-0.2mm	Voltage DC	16 VDC (85C), 1
5mm +/-0.2mm 13mm REF	Voltage DC Temperature Range	16 VDC (85C), 1 -55/+125°C
5mm +/-0.2mm 13mm REF 8mm +0.2/-0.3mm	Voltage DC Temperature Range Rated Temperature	16 VDC (85C), 1 -55/+125°C 85°C

**General Information** 

Series

Style

Dielectric

Description

Features

Dimensions	
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
н	1.6mm +/-0.2mm
т	0.13mm REF
S	0.8mm +0.2/-0.3mm
F	1.2mm +/-0.1mm
Α	1.2mm MIN
В	0.4mm +/-0.15mm
E	1.3mm REF
G	1.1mm REF
Р	0.4mm REF
R	0.4mm REF
Х	0.1mm +/-0.1mm REF

Capacitance	1.5 uF
Tolerance	10%
Voltage DC	16 VDC (85C), 10.72 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	5000 mOhms (100kHz 25C)
Ripple Current	122 mA (rms, 100kHz 25C), 109.8 mA (rms, 85C), 48.8 mA (rms, 125C)
Leakage Current	0.5 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

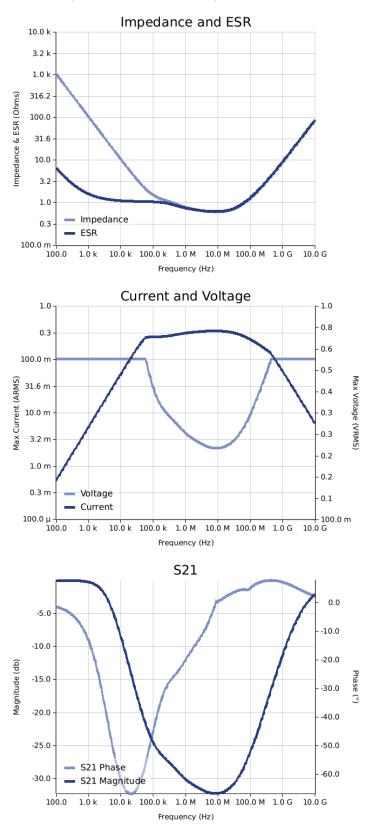
Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.



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## Simulations

For the complete simulation environment please visit K-SIM.



Magnitude (db)

-15.0

-20.0

-25.0

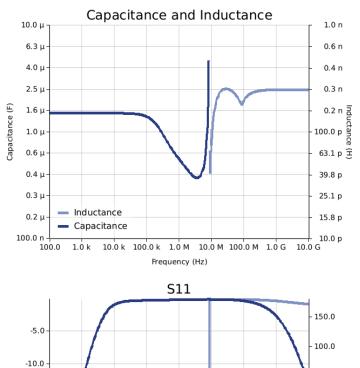
-30.0

100.0

S11 Phase

1.0 k

S11 Magnitude



10.0 k 100.0 k 1.0 M 10.0 M 100.0 M 1.0 G 10.0 G

Frequency (Hz)

50.0

0.0

-50.0

-100.0

-150.0

Phase (°)



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## These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated. The effects shown herein are based on measured data from a multiple part sample of the parts in question. Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance. The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.
  Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.